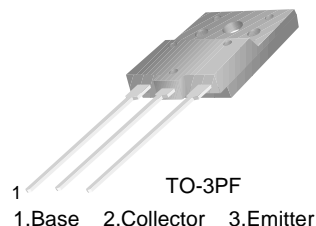


# KSD5707

KSD5707

## High Voltage Color Display Horizontal Deflection Output

- High Collector - Base Voltage :  $V_{CBO} = 1500V$
- High Speed Switching  $t_f = 0.4\mu s$  (Max.)



## NPN Triple Diffused Planar Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	1500	V
$V_{CEO}$	Collector-Emitter Voltage	800	V
$V_{EBO}$	Emitter-Base Voltage	6	V
$I_C$	Collector Current (DC)	6	A
$I_{CP}$	Collector Current (Pulse)	16	A
$P_C$	Collector Dissipation ( $T_C=25^\circ C$ )	60	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	- 55 ~ 150	$^\circ C$

### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 800V, I_E = 0$			10	$\mu A$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 5V, I_C = 0$			1	mA
$h_{FE1}$	DC Current Gain	$V_{CE} = 5V, I_C = 1A$	10		30	
$h_{FE2}$		$V_{CE} = 5V, I_C = 3A$	5		15	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 4A, I_B = 0.8A$		2	5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 4A, I_B = 0.8A$			1.5	V
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10V, I_C = 1A$		3		MHz
$t_f$	Fall Time	$V_{CC} = 200V, I_C = 4A,$ $I_{B1} = 0.8A, I_{B2} = -1.6A$ $R_L = 50\Omega$			0.4	$\mu s$

### Thermal Characteristics

Symbol	Characteristics		Rating	Unit
$R_{\theta jc}$	Thermal Resistance	Junction to Case	2.08	$^\circ C/W$

# Typical Characteristics

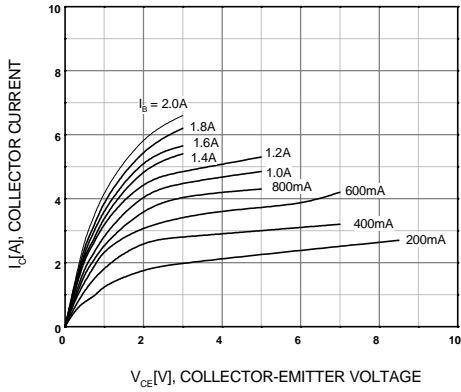


Figure 1. Static Characteristic

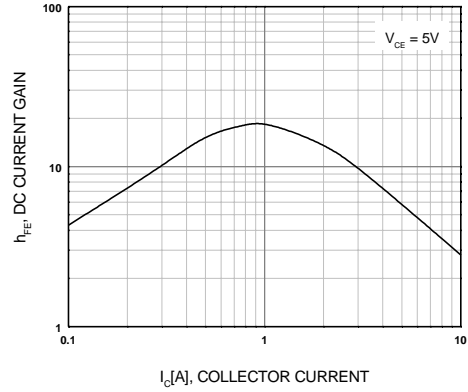


Figure 2. DC current Gain

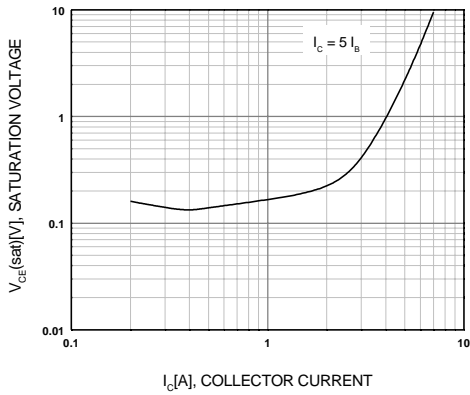


Figure 3. Collector-Emitter Saturation Voltage

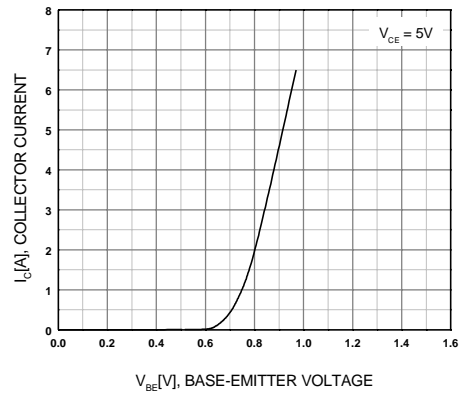


Figure 4. Base-Emitter On Voltage

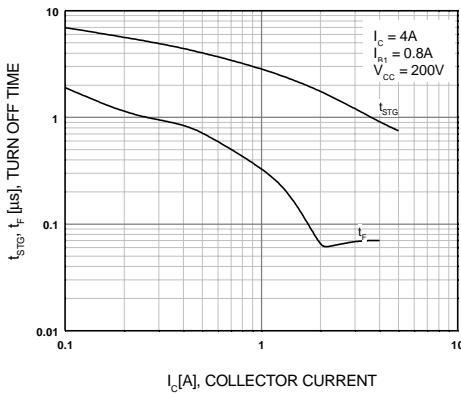


Figure 5. Switching Time

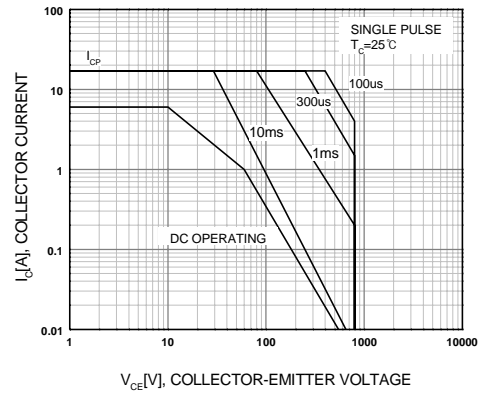


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

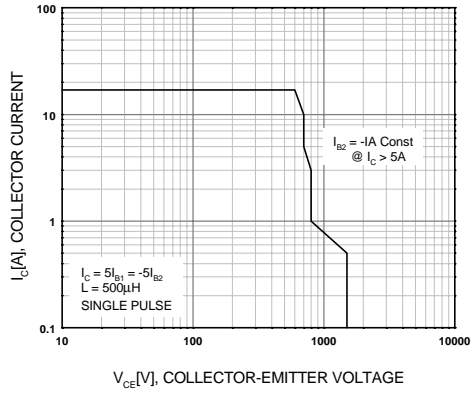


Figure 7. Reverse Bias Safe Operating Area

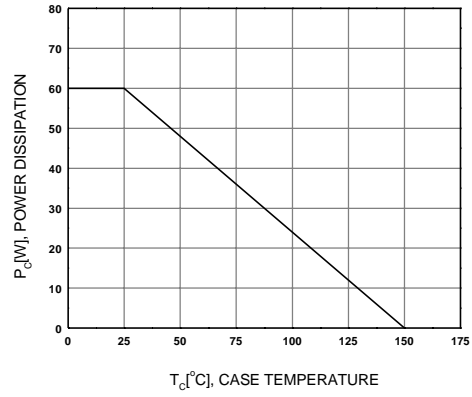
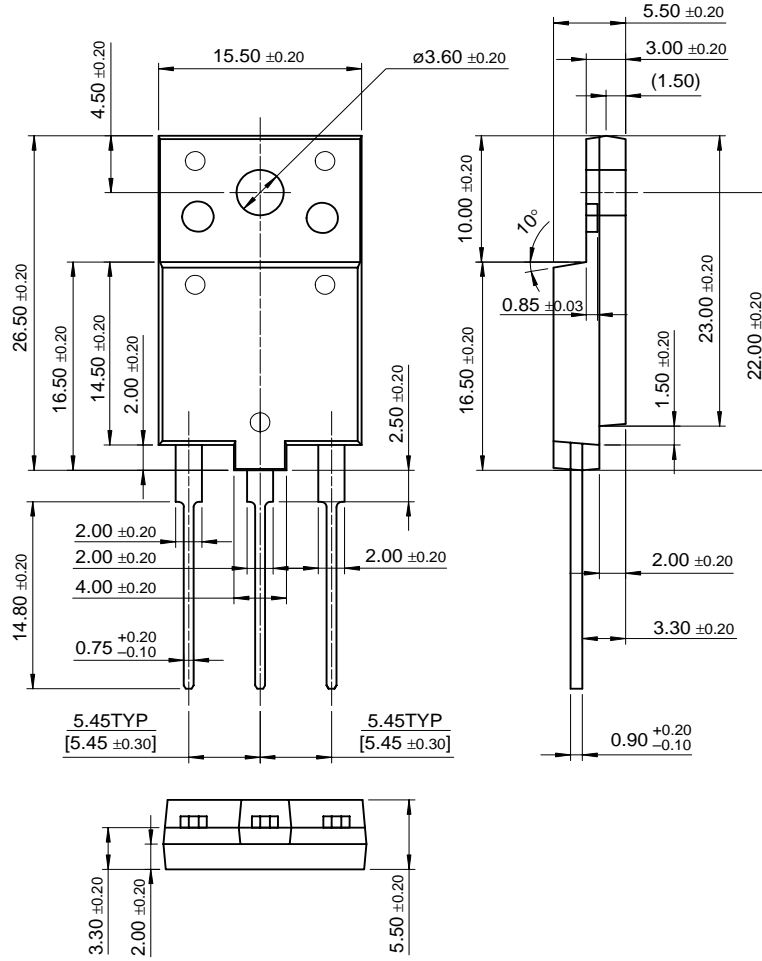


Figure 8. Power Derating

# Package Dimensions

## TO-3PF



Dimensions in Millimeters

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